



WIR SCHAFFEN WISSEN – HEUTE FÜR MORGEN

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Creating and Tuning Electronic states, and Phases of NdNiO_3

Workshop on New Horizons in Quantum Correlated Materials
ICTP-SAIFR, São Paulo, Brazil
August 15-19, 2022

Creation and Control of the electronic properties of ABO_3

Distortion of the BO_6 octahedron



Energy splitting of the d_{xy} & d_{xz} & d_{yz} bands

Doping (through A)



Filling of the bands

Octahedral rotations, Binding angles



Hopping probability,
Effective mass
Band width

Proximity effects

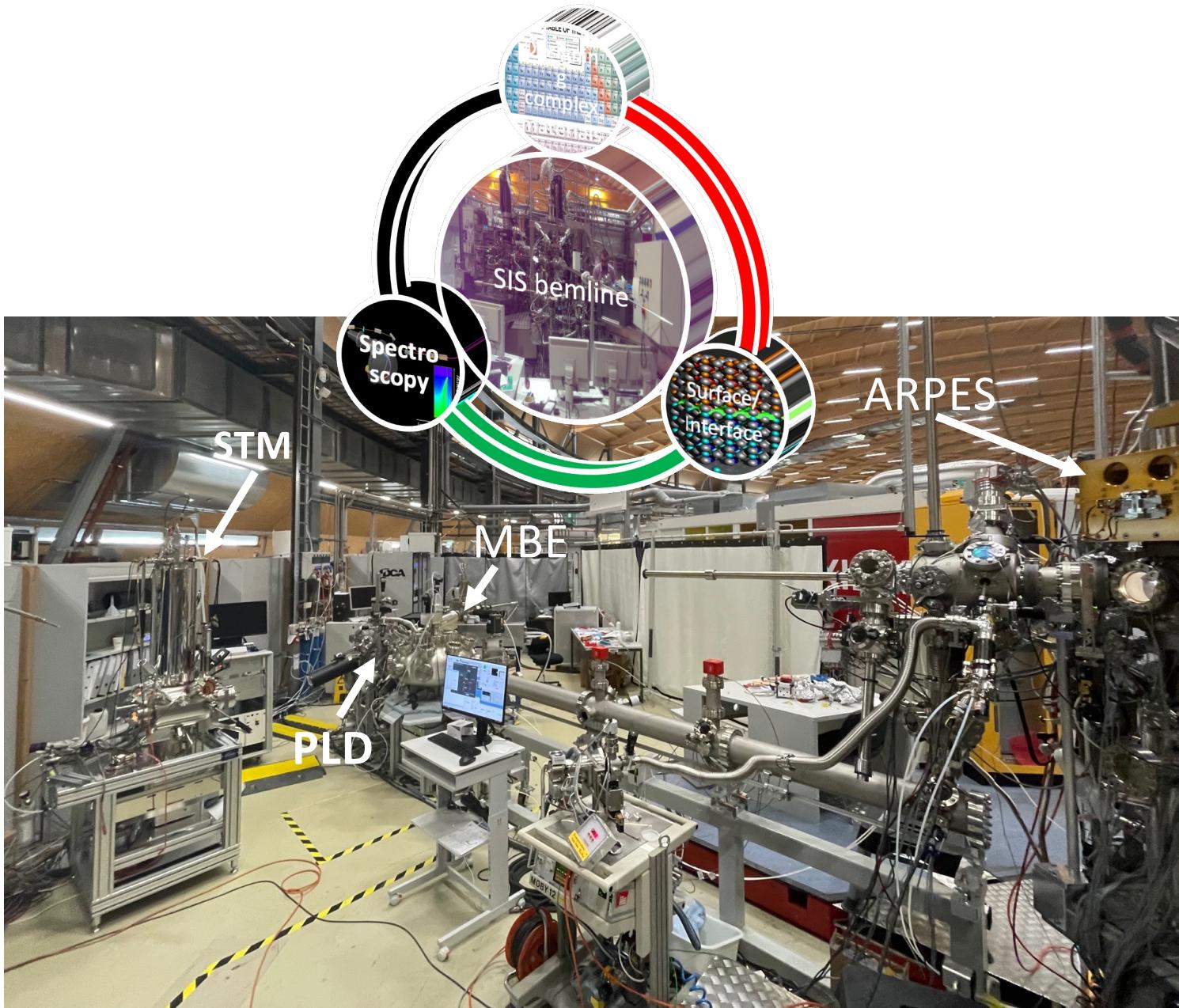


Doping via charge transfer,
Inducing orders
(magnetism
superconductivity...)

How to turn the knobs?

- ✓ Defect Engineering;
- ✓ Altering crystal structure;
 - ✓ Lattice strain,
 - ✓ Proximity
 - ✓ ...

The modular system at the SIS beamline (ARPES+ PLD+STM+MBE) for developing functional materials with novel quantum properties



The new beamline at SLS 2.0

QUEST (QUantum matter Electron Spectroscopy Tool)

M. Muntwiller, T. Jung, M. Shi, T. Schmitt, N. Plumb, M.R.

- 2 end stations –

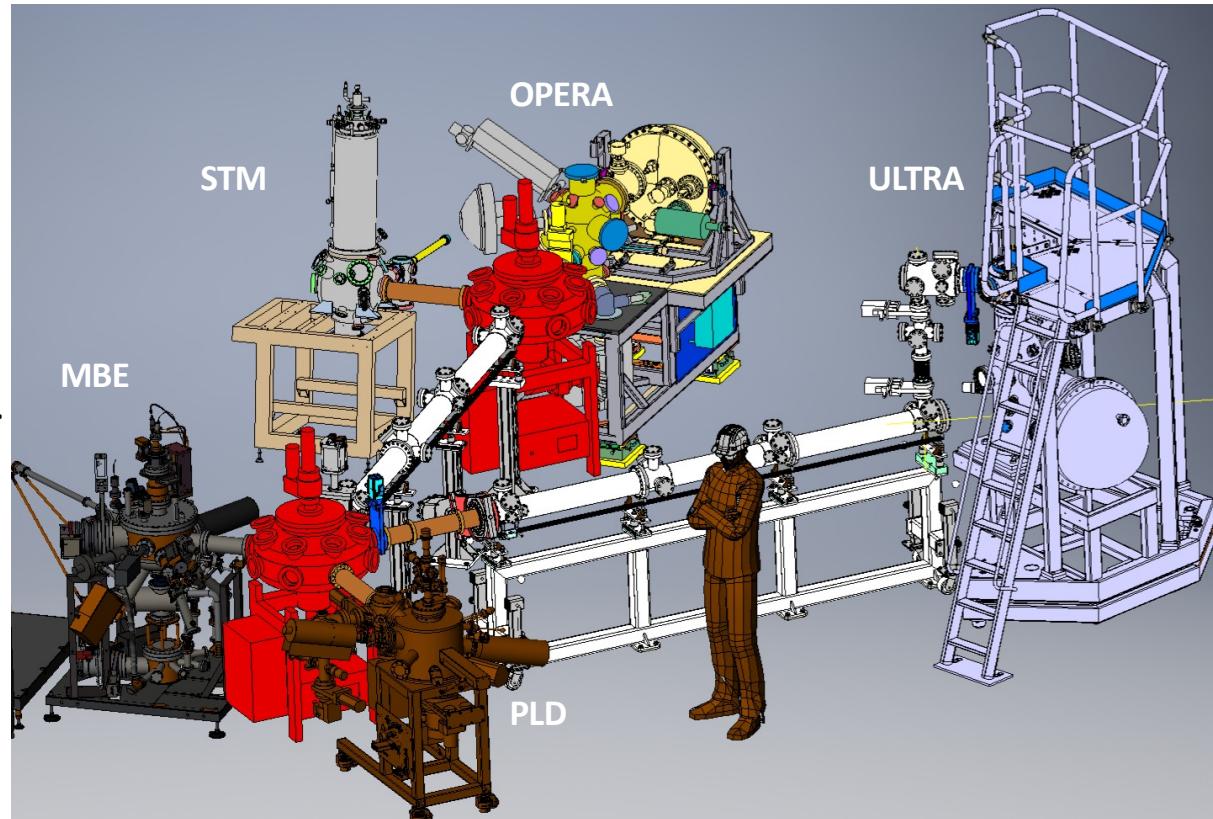
- **ULTRA**: low temperature, high resolution + spin detection.
- **OPERA** end station: complex systems, operando, micro-focus.

- Advanced sample preparation.

methods: PLD, MBE,...

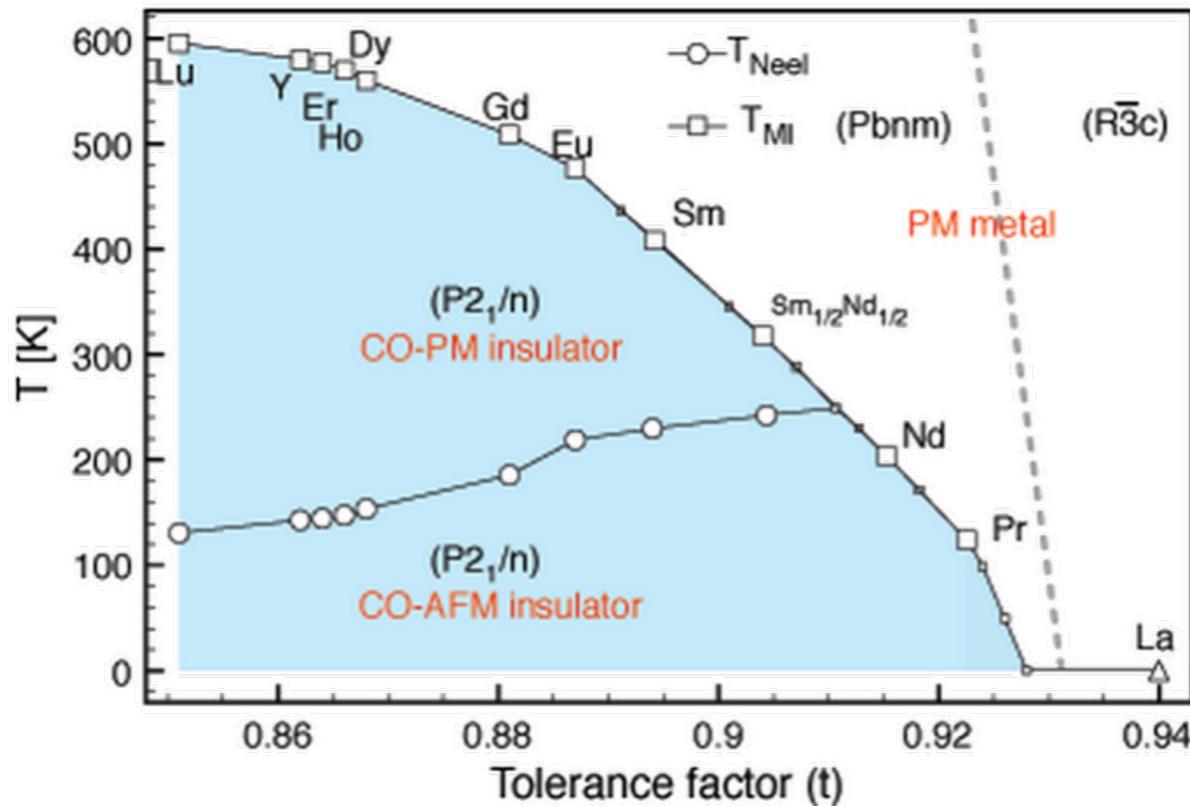
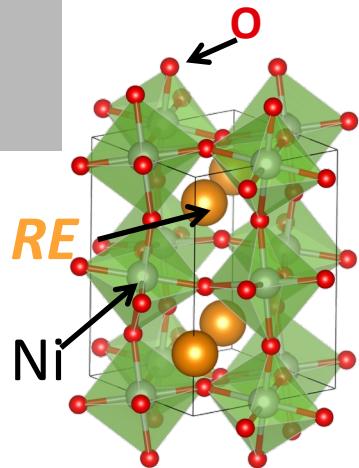
- Complementary instrumentation

STS, STM, AFM.



Creating and Tuning Electronic states, and Phases of NdNiO_3

overview and motivation



bond length

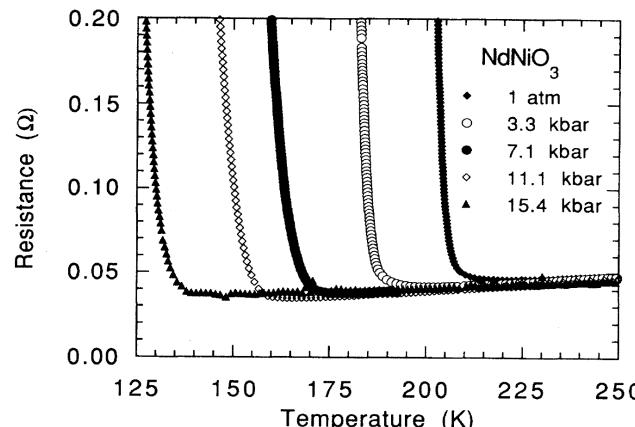
$$t \equiv \frac{(\text{RE}-\text{O})}{\sqrt{2}(\text{Ni}-\text{O})}$$

bond length

$0.7 < t < 9$: orthorombic,
(Ni-O) bonds **under a tensile stress**

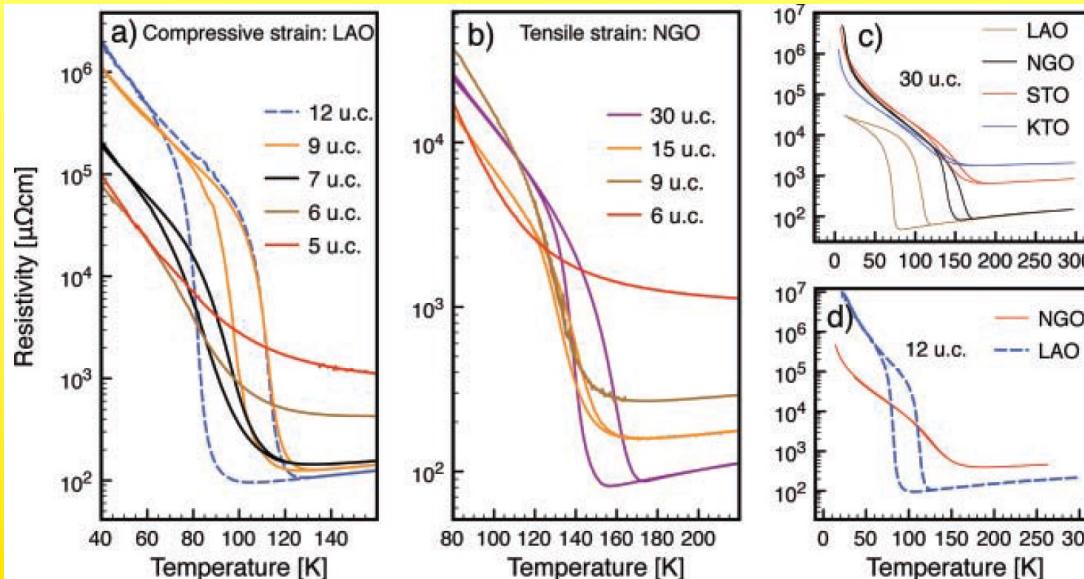
Tuning MIT in NdNiO_3 via strain and “dimensionality”

- External pressure

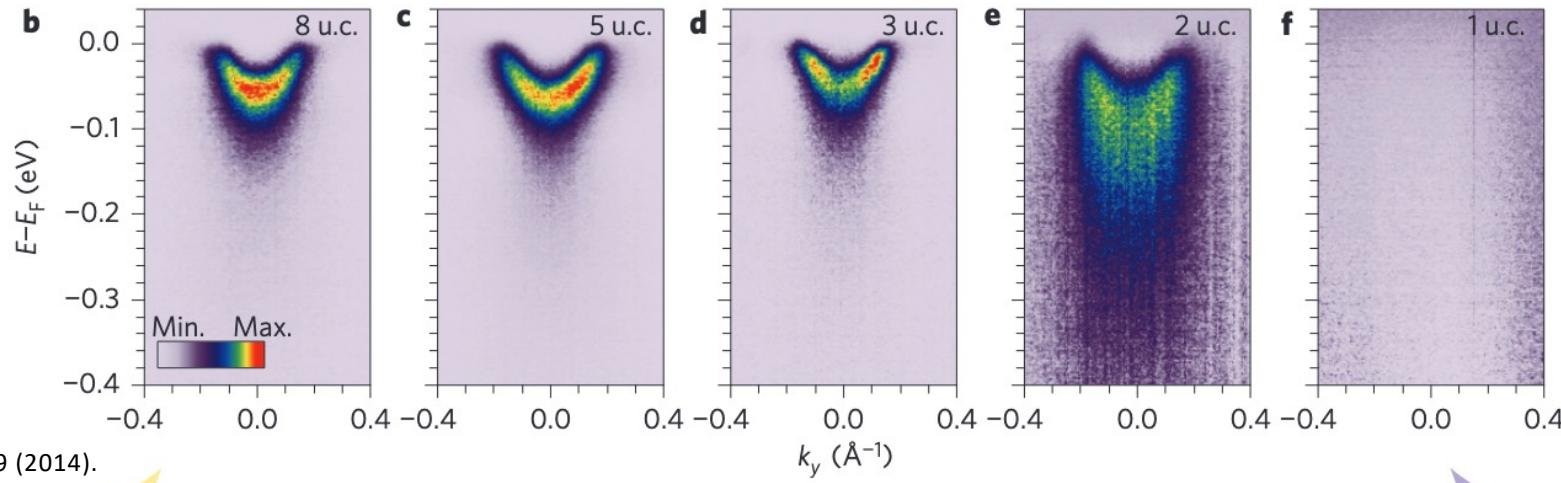


X. Obradors et al., Phys. Rev. B 47, 12353, 1993.

- Strain and thickness (in NdNiO_3 thin films)



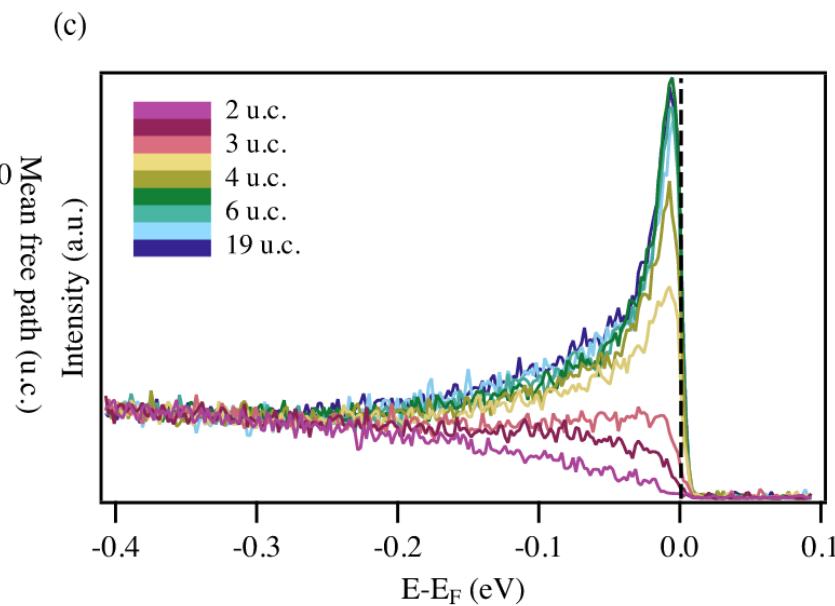
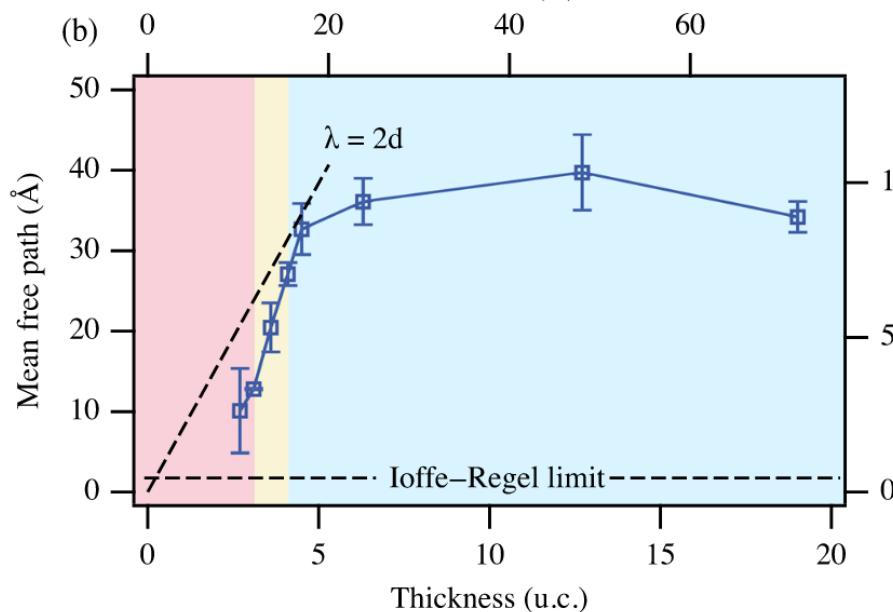
R. Scherwitzl et al.; Adv. Mater. 22, 5517–5520, 2010

Tuning MIT in LaNiO_3 via “dimensionality”/thickness: ARPES view

P. D. C. King et al.,
Nature Nanotech. 59, Vol 9 (2014).

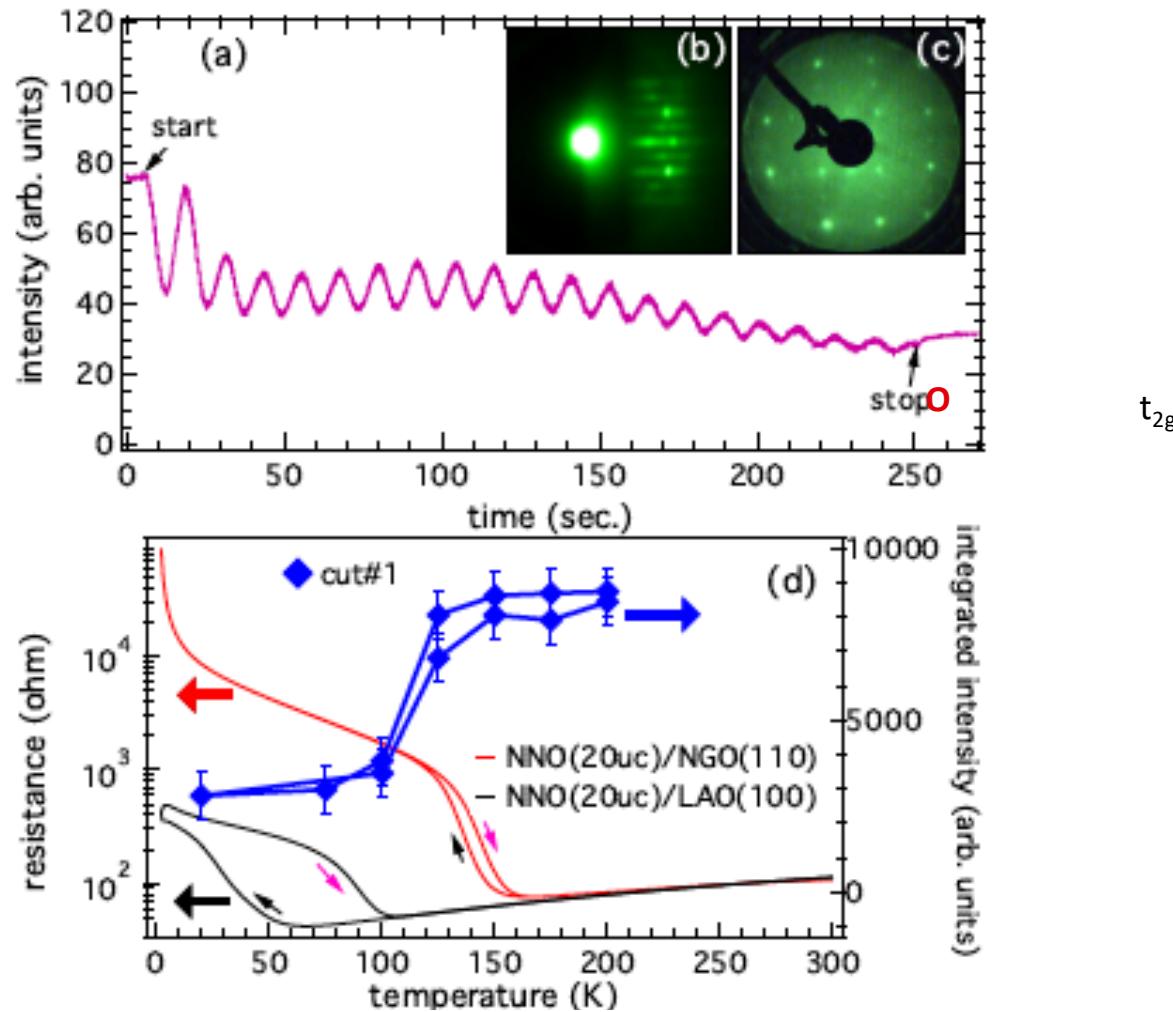
Increasing metallicity

Decreasing film thickness



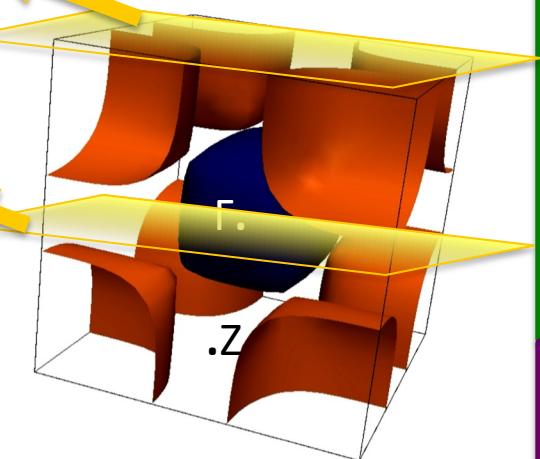
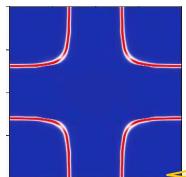
Tuning MIT in NdNiO_3 via strain: What does happen?

NdNiO_3 on NGO (110) and LAO (100)

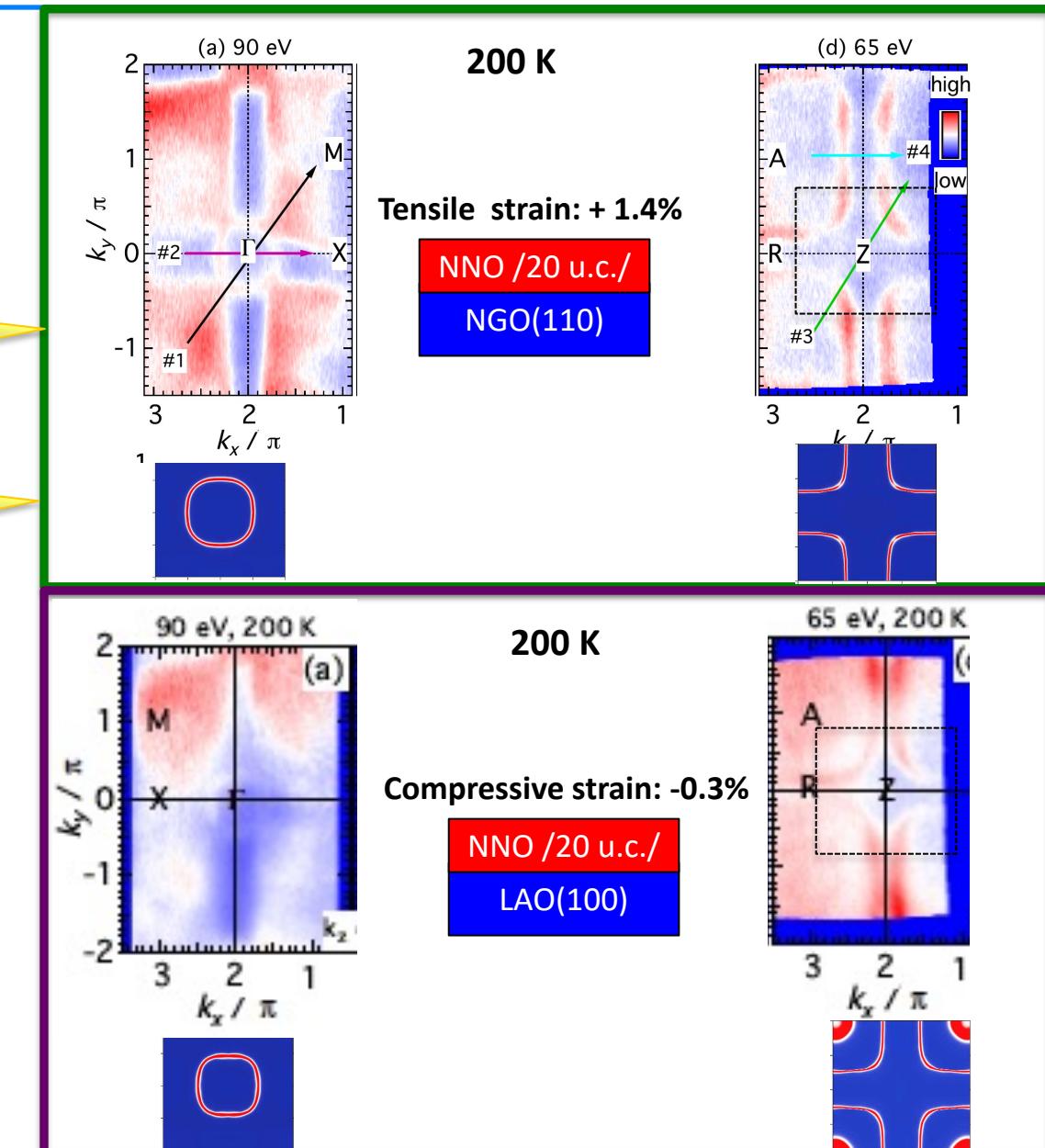
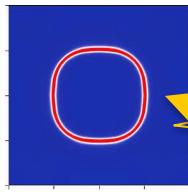


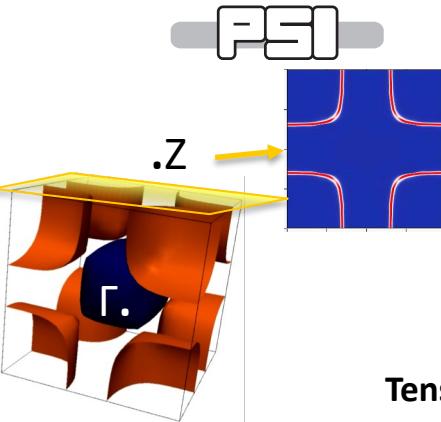
Tuning MIT in NdNiO_3 via strain: What happens?

FS at Z point



FS at Gamma



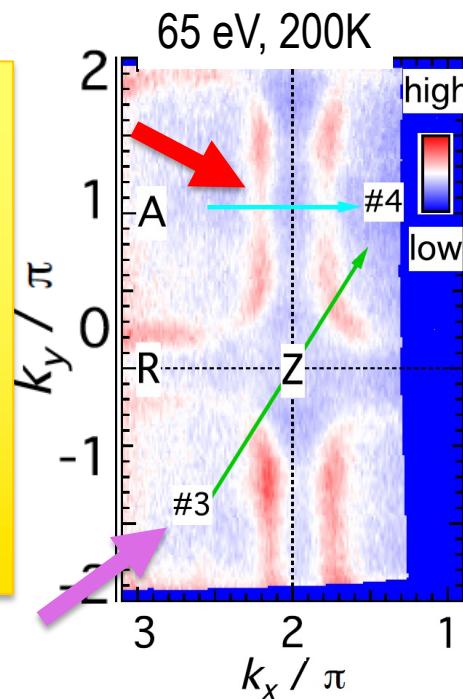


Tuning MIT in NdNiO_3 via strain: What does happen?

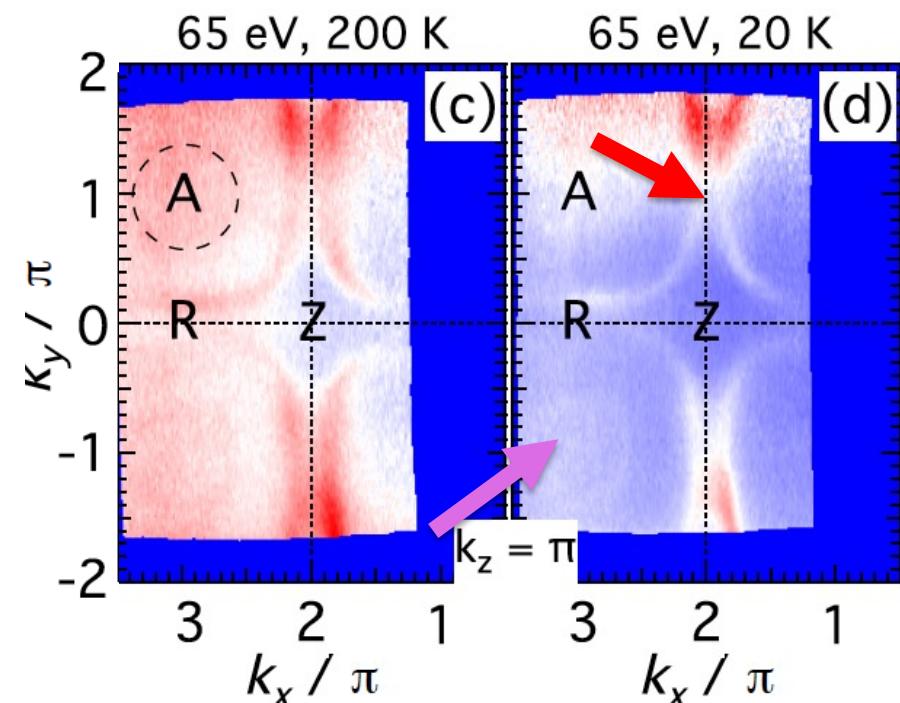
Tensile strain: + 1.4%



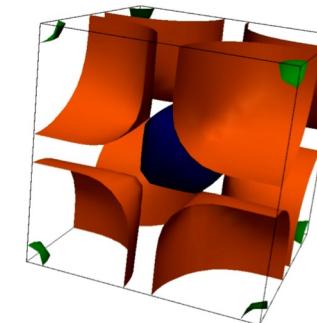
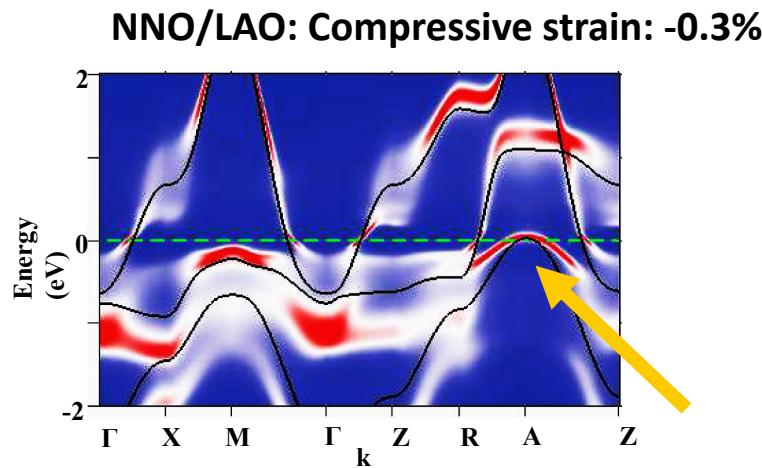
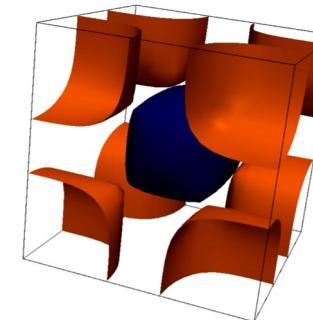
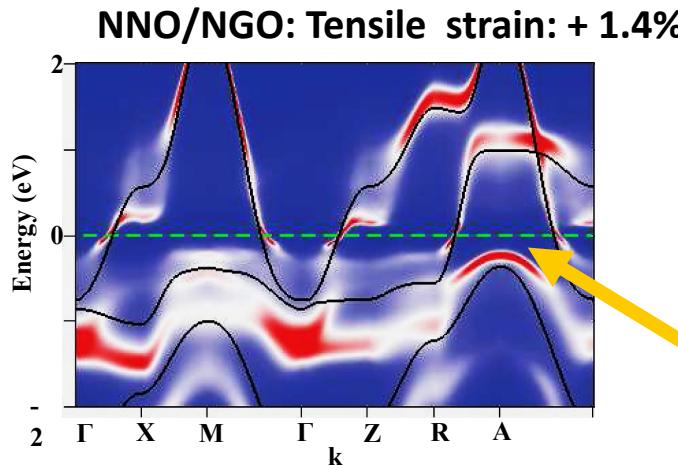
20K Insulator
phase
NO FS



Compressive strain: -0.3%



Tuning MIT in NdNiO₃ via strain: What does happen?

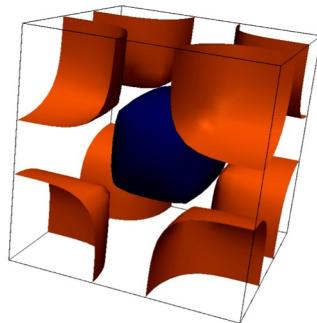


The momentum dependent density fluctuations (MRDF) modeling

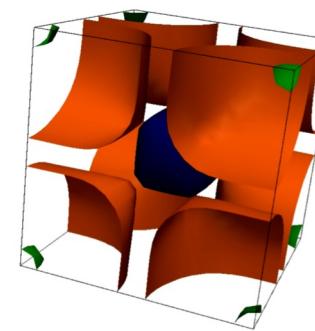
R. Dhaka, et al., Phys. Rev. B 92, 035127, 2015

Tuning MIT in NdNiO₃ via strain: What does happen?

NNO/NGO: Tensile strain

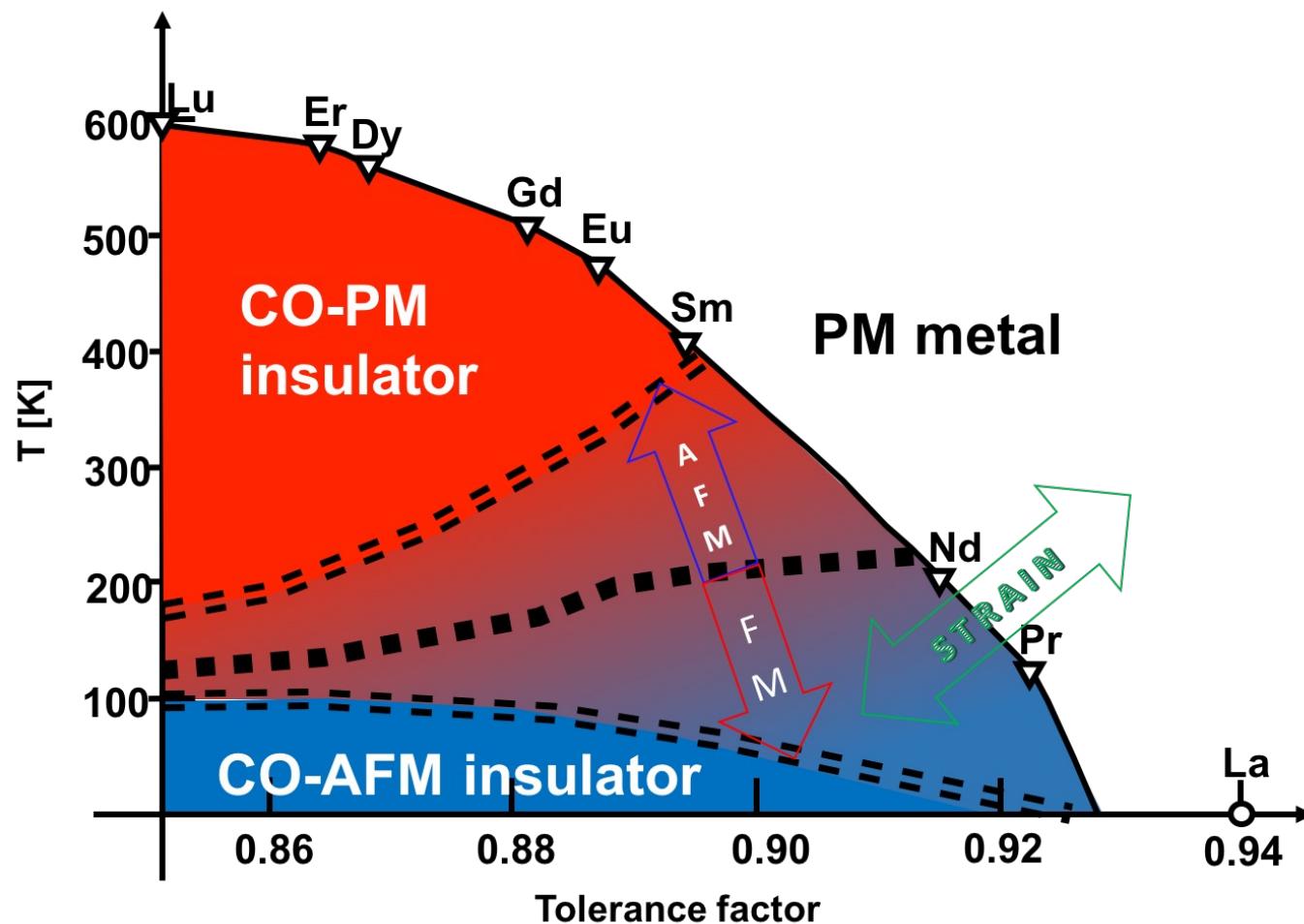


NNO/LAO: Compressive strain

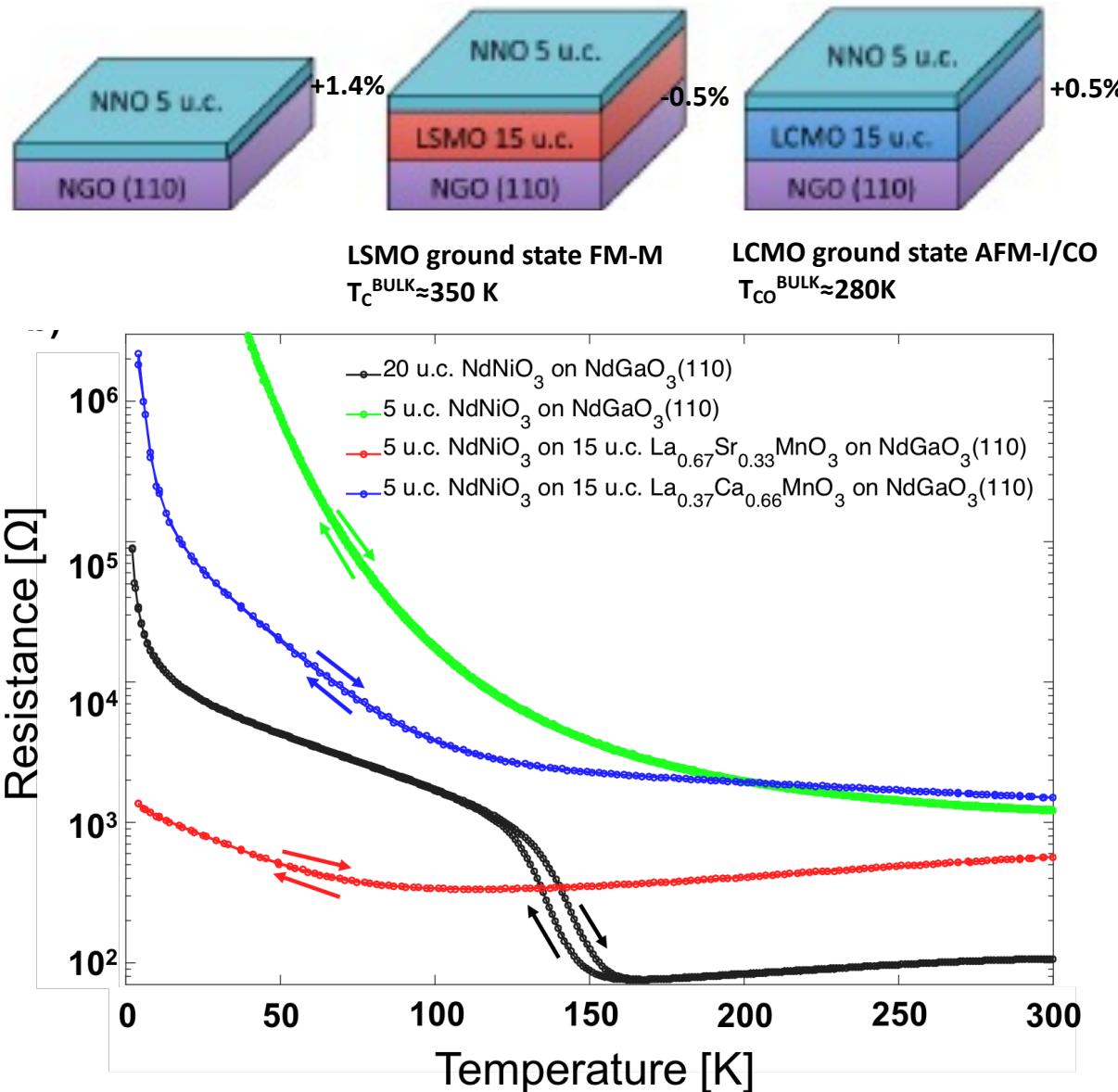


- Reduces MIT: 150 K compared to the bulk value of 200K
- Electronic structure: roughly the same as calculated for the unstrain system
- Significantly reduces MIT (50 K)
- Electronic structure: much different than calculated for the untrain system:
 - e_g orbitals are lowered and
 - t_{2g} orbitals are lifted.
 - The new, hole like, Fermi surface at A point.

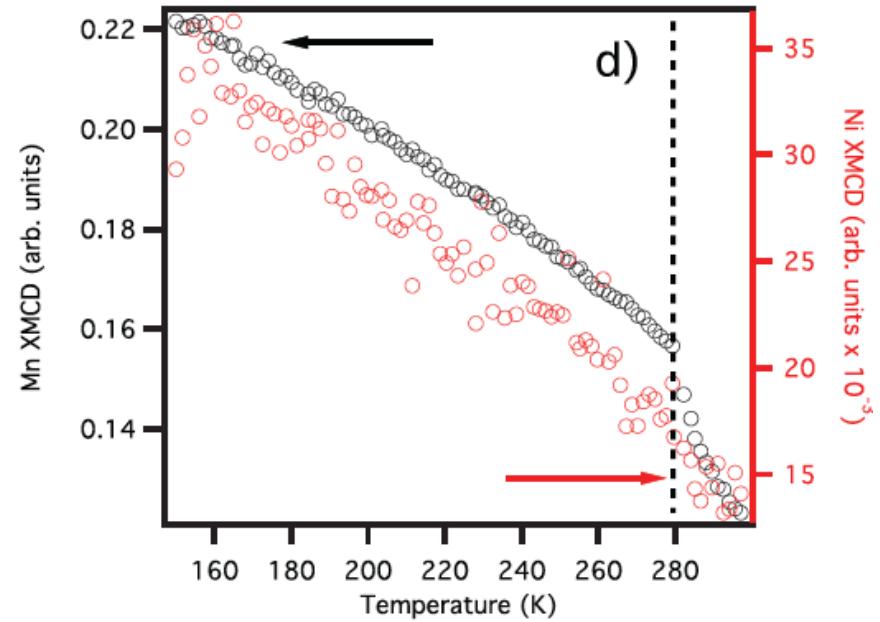
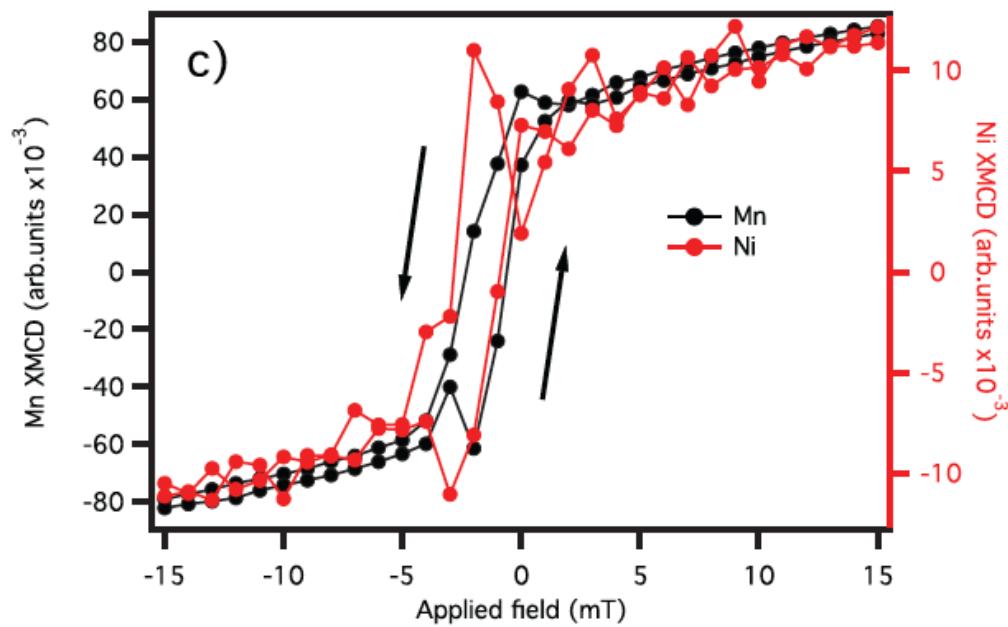
ReNiO₃-Creating and Tuning Electronic states, and Phases



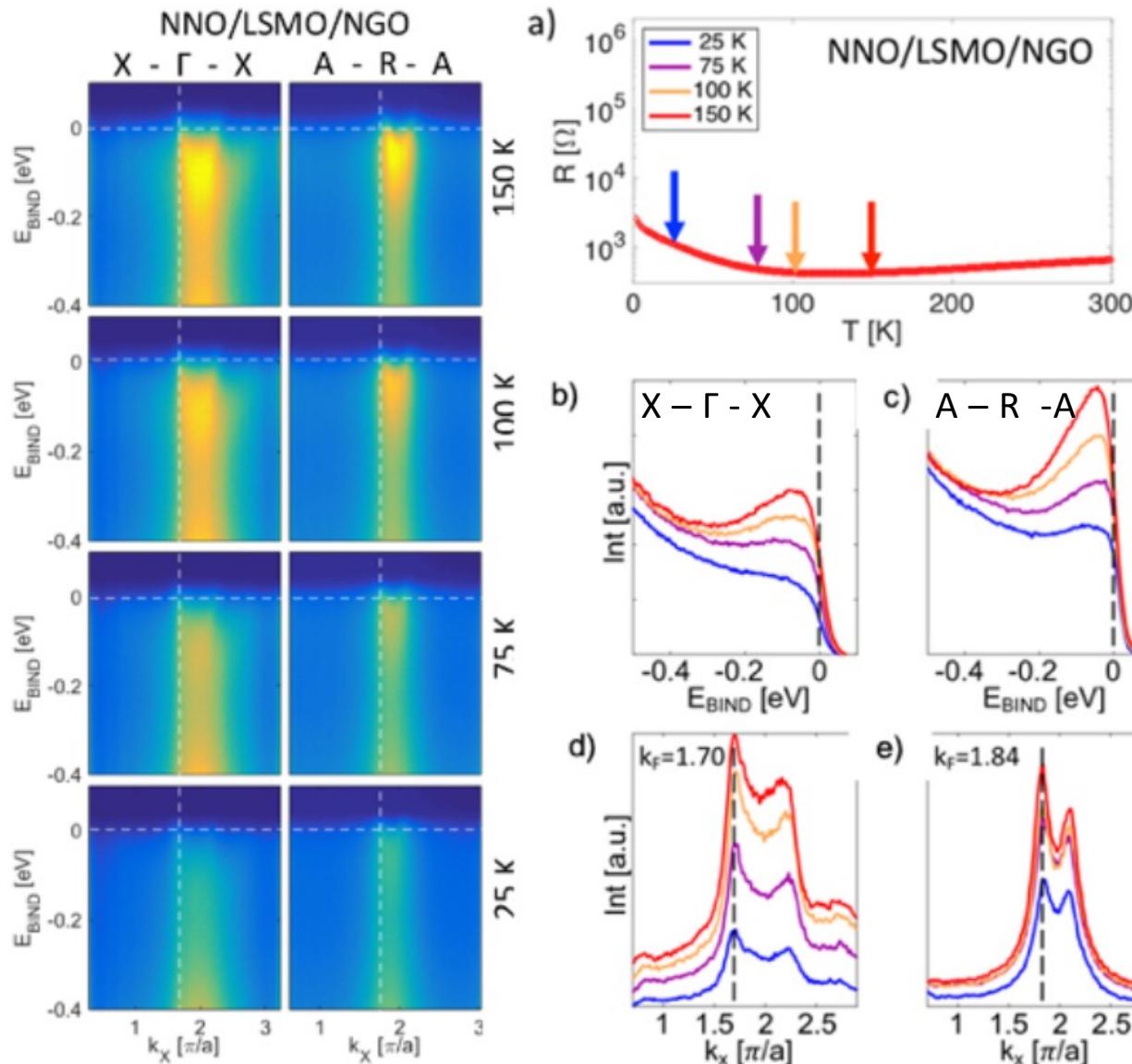
Tuning PHASE transition in NdNiO_3 Films via a Magnetic Underlayer



Tuning PHASE transition in NdNiO_3 Films via a Magnetic Underlayer

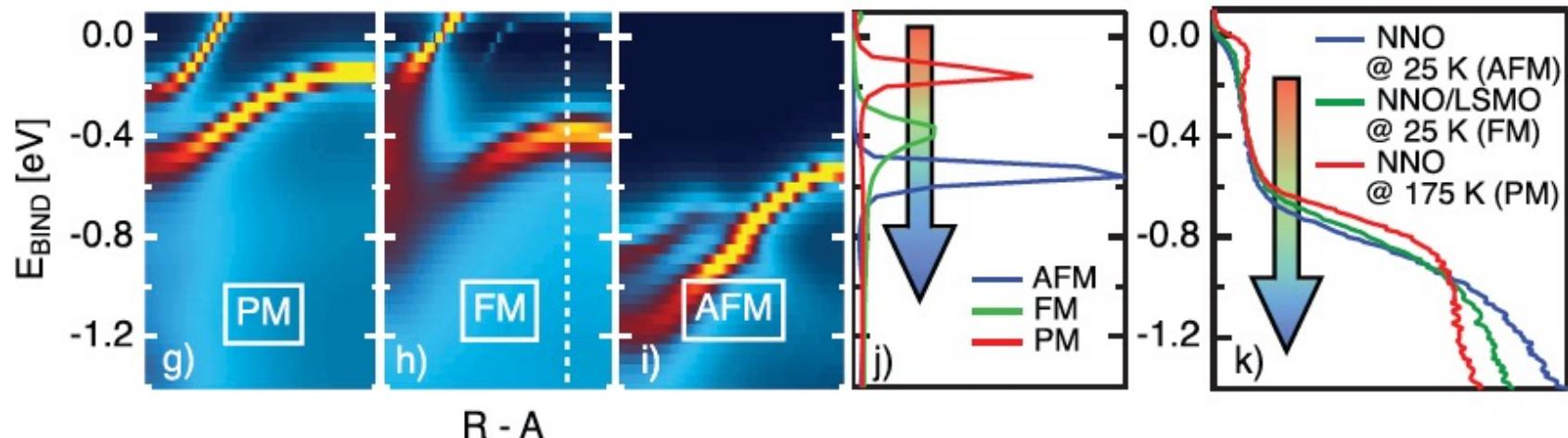
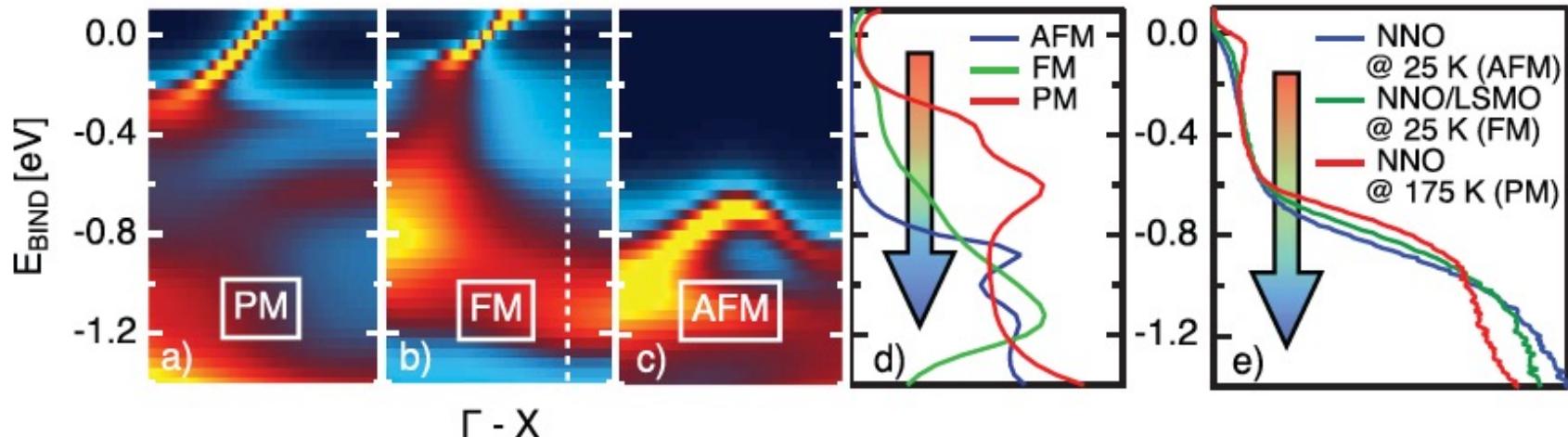


Tuning PHASE transition in NdNiO_3 Films via a Magnetic Underlayer: ARPES view

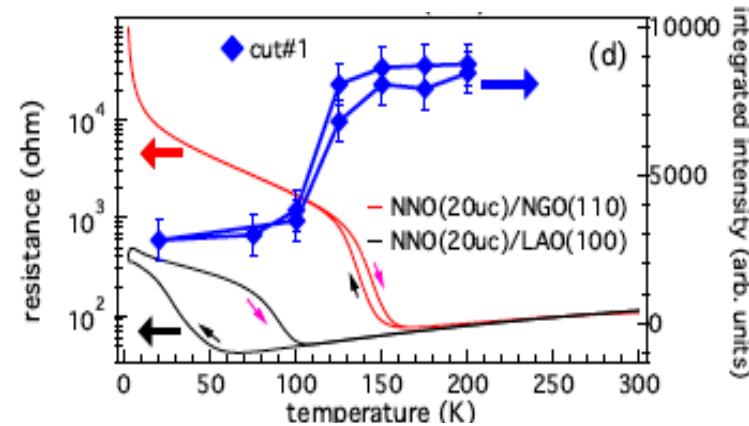
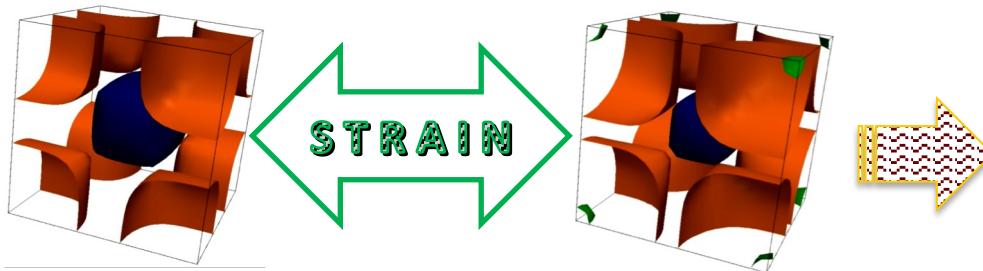


Tuning PHASE transition in NdNiO_3 Films via a Magnetic Underlayer: ARPES view

Momentum Dependent Density Fluctuations Modeling



Tuning of ELECTRONIC states...



...and Creating the new PHASE of NdNiO₃

